MN39116AT

Diagonal 4.5 mm (type-1/4) 270k-pixel CCD Area Image Sensor

Overview

The MN39116AT is a 4.5 mm (type-1/4) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal readout. The electronic shutter function has made an exposure time of 1/10000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of 267 206 pixels (542 horizontal \times 493 vertical) and provides stable and clear images with a resolution of 360 horizontal TV-lines and 350 vertical TV-lines.

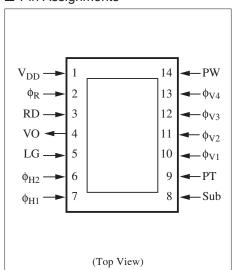
Part Number	Size	System	Color or B/W		
MN39116AT	4.5 mm (type-1/4)	EIA	B/W		

Features

- Effective pixel number 512 (horizontal) × 491 (vertical)
- High sensitivity
- Broad dynamic range
- Low smear
- Electronic shutter

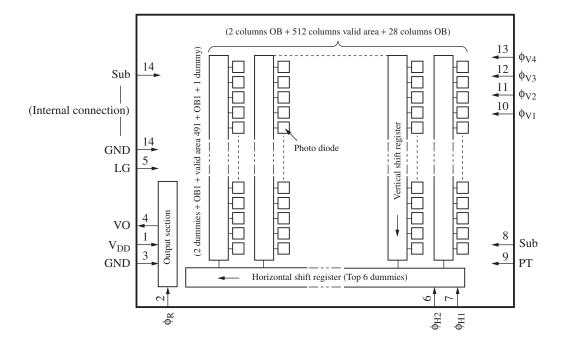
Applications

- Surveillance cameras
- FA, OA cameras



Pin Assignments

Block Diagram



Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	V _{DD}	Power supply	8	Sub	Substrate
2	φ _R	Reset pulse (RG)	9	РТ	P-well for protection circuit
3	RD	Reset drain	10	φ _{V1}	Vertical shift register clock pulse 1
4	VO	Video output	11	ϕ_{V2}	Vertical shift register clock pulse 2
5	LG	Output load transistor gate	12	φ _{V3}	Vertical shift register clock pulse 3
6	ф _{Н2}	Horizontal register clock pulse 2	13	ϕ_{V4}	Vertical shift register clock pulse 4
7	$\phi_{\rm H1}$	Horizontal register clock pulse 1	14	PW	P-well

■ Device Parameter (H × V)

Parameter	Value	Unit
Pixel number *	512 × 491	pixel
Image sensing block dimension	3.6144×2.716	mm ²
Pixel dimension	7.2 × 5.6	μm ²

Note) *: OB columns are not included.

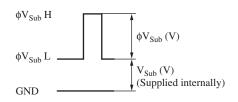
Absolute Maximum Ratings and Operating Conditions

Parameter		Absolute maximum rating		Operating condition			
		Lower limit	Lower limit Upper limit		Min Typ		Unit
V _{DD}		- 0.2	18.0	14.5	15.0	15.5	V
V _{RD}		- 0.2	18.0	14.5	15.0	15.5	V
V _{PT} * ^{3, 4}		-10.0	0.2	-8.3	-8.0	-7.7	V
GND		(Refere	ne voltage)		0		V
V _{LG} *6			(\$	upplied internal	lly)		V
V _{OG}			(\$	upplied internal	lly)		V
V _{¢R}	High-Low		8.0	3.0	3.3	5.3	V
	Bias	(Supplied internally)				V	
V _{oH1}	High		8.0	3.0	3.3	5.3	V
	Low	- 0.2		- 0.05	0	0.05	V
V _{¢H2}	High		8.0	3.0	3.3	5.3	V
	Low	- 0.2		- 0.05	0	0.05	V
V _{Sub} *2		(Supplied internally)					V
φV _{Sub} *1		- 0.2	45.0	22.5	23.0	23.5	V
V _{\$\phiV1} *3, 4, 5	High		18.0	14.5	15.0	15.5	V
	Middle		_	- 0.2	0	0.2	V
	Low	-9.0	_	-8.3	-8.0	-7.7	V
V _{\$\phiV2} *3, 4, 5	Middle		15.0	- 0.2	0	0.2	V
	Low	-9.0	_	-8.3	-8.0	-7.7	V
$V_{\phi V3}$ *3, 4, 5	High		18.0	14.5	15.0	15.5	V
	Middle	_	_	- 0.2	0	0.2	V
	Low	-9.0	_	-8.3	-8.0	-7.7	V
$V_{\phi V4} *3, 4, 5$	Middle		15.0	- 0.2	0	0.2	V
	Low	-9.0	_	-8.3	-8.0	-7.7	V
Operating temperature		-10	60		25		°C
Storage temperature		-30	80	_	_		°C

Note) 1. Standard photo detecting condition

Standard photo detecting condition stands for detecting image with a light source of color temperature of 2 856K, luminance of 1 050 cd/m², and using a color temperature conversion filter LB-40 (HOYA), infrared cut filter CAW-500S with thickness 2.5 mm for a light path and with F8 lens aperture. The quantity of the incidental light to a photo-detecting surface under the above condition is defined as the standard quantity of light.

2. *1: V_{Sub} when using electronic shutter function



Absolute Maximum Ratings and Operating Conditions (continued)

Note) 2. *2: V_{Sub} supplied internally is the voltage suppressing the blooming generation at ×1 000 light quantity relative to the standard light quantity.

*3: Relation between V_{PT} and $V_{\phi VL}$

Set V_{PT} under the following condition against VL of a vertical transfer clock waveform.

$$V_{PT} \leq VL \; (V_{\varphi V1L} \; \text{to} \; V_{\varphi V4L})$$

*4: Absolute maximum ratings $-0.2 < V_{Sub} - V_{PT} < 55 (V)$

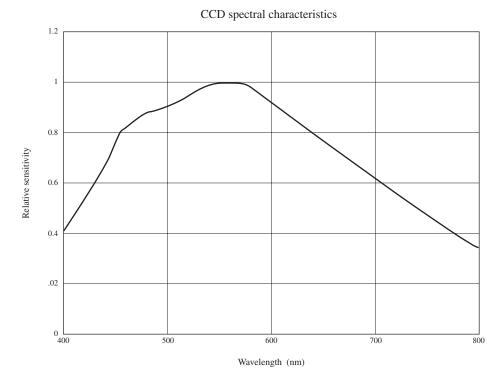
$$0.2 < V_{\phi V} - V_{PT} < 24.5 (V)$$

*5: Ground LG pin with the capacitor of 0.047 μ F or more. Ground ϕ_R pin with the capacitor of 1 M Ω .

Optical Characteristics

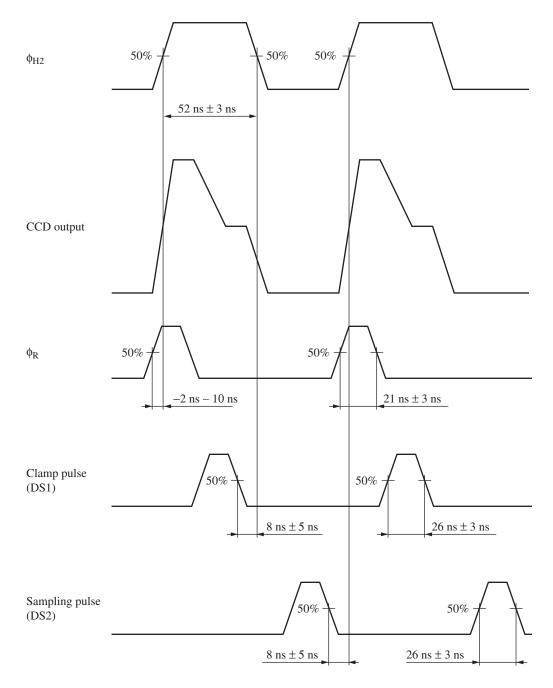
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
S/N ratio (dark)	S/Nd	Dark condition	58	60		dB
Sensitivity	So	J chart F8	480	650		mV
Saturation output	Sc	Saturation maximum output	700	900		mV
Vertical smear	Sm	1/10 V chart, F2.8			0.01	%

Graph of Characteristics



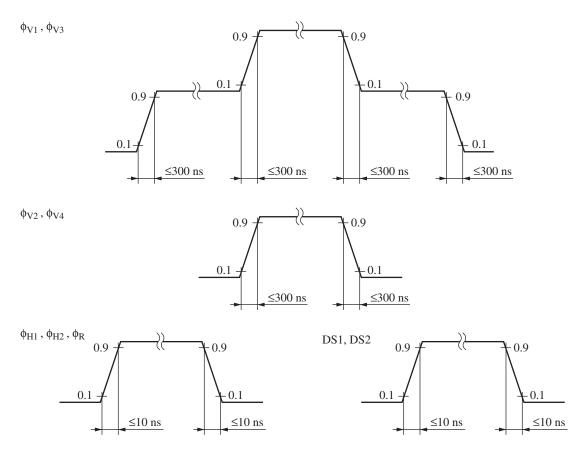
■ Timing Diagram

• High speed pulse timing

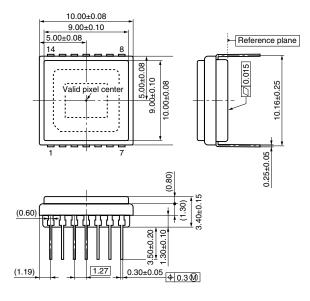


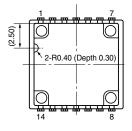
■ Timing Diagram (continued)

• Rise time and fall time of each pulse



- Package Dimensions (unit: mm)
- WDIP014-P-0400F





- 1. The center of the package is equal to the center of the effective pixel area.
- 2. The rotation angle of the effective pixel area: up to ± 1.0 degree
- 3. The distance from the bottom face of the package to the surface of the effective pixel area: 1.69 mm \pm 0.10 mm
- 4. The tilt of the effective pixel area for the bottom face of the package: up to 25 μ m
- 5. Thickness of seal glass is 0.8 mm, and the refractive index is 1.50.
- 6. Package weight: 0.65 g (typ.)

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